NSN 5961-01-165-0590

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-165-0590 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 1.500 inches **Overall Diameter:** 0.195 inches **Internal Configuration:** Junction contact-double emitter Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, emitter-to-base, collector open and 50.0 breakdown voltage, emitter to collector, base open and 50.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 10.00 nanoamperes zero-gate-voltage source current preset **Transfer Ratio:** 1.5 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No